

CLAIMS

We claim:

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- 1 A memory module for use in a memory system comprising:
- 10 a first memory module including a memory device and a first buffer, the first buffer receiving a first write clock signal and a control signal that includes a read or write command in a first direction of transmission, a second buffer receiving the first write clock signal in the first direction of transmission and a first read clock signal in a second direction of transmission, the second buffer being coupled to a first data bus and a second data bus;
- 15 the first memory module generating a second write clock signal in response to the first write clock signal for transmitting data from the second buffer in the first direction of transmission if the write command indicates that data is to be written to a second memory module in the memory system, and generating a memory write clock signal in response to the first write clock signal for writing data from the second buffer to the memory device if the write command indicates that data is to be written to the memory device in the first memory module; and
- 20 the first memory module generating a memory read clock signal in response to a memory write clock signal for reading data from the memory device to the second buffer if the read command indicates that data is to be read from the memory device in the first memory module; the memory write clock signal being generated in response to the first write clock signal.
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- 2 The memory module of claim 1 wherein the memory module further generates a second read clock signal in response to the first write clock signal for transmitting data from the second buffer in the second direction of transmission.
- 3 The memory module of claim 1 wherein the memory read clock signal is a clock signal returned from the memory device in response to the memory write clock signal.

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4 The memory module of claim 3 wherein the memory read clock signal is generated on a transmission path that is coupled to a transmission path of the memory write clock signal.

5 5 The memory module of claim 4 further comprising a dummy load coupled to the transmission path of the memory read clock signal and the memory write clock signal.

6 The memory module of claim 4 wherein the transmission path of the memory read clock signal and the transmission path of the memory write clock signal are substantially equal in length to that of a transmission path of the data signals between the memory and the second buffer.

7 The memory module of claim 1 wherein the second write clock signal is generated in response to the first write clock signal such that the second write clock signal is transferred to the second buffer on the second memory module .

8 The memory module of claim 7 wherein the second write clock signal is generated by a phase locked loop or delay locked loop on the first memory module in response to the first write clock signal.

9 The memory module of claim 1 wherein the second buffer receives a decoding signal generated at the first buffer to determine whether data access is from the memory device on the first memory module or the memory device on the second memory module

10 10 The memory module of claim 1 wherein the first buffer receives a first latency signal and transfers the buffered first latency signal to the memory device in response to the first write clock signal

11 The memory module of claim 10 wherein the first buffer generates a second latency signal

12 A memory module for use in a memory system comprising:

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13 The memory module of claim 12 wherein the first memory module generates a memory write clock signal in response to the first write clock signal for writing data from the second buffer to the memory device if the write command indicates that data is to be written to the memory device in the first module.

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14 The memory module of claim 12 wherein the first memory module generates a memory read clock signal in response to a memory write clock signal for reading data from the memory to the second buffer if the read command indicates that data is to be read from the memory device in the first module, the memory write clock signal being generated in response to the first write clock signal.

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15 The memory module of claim 14 wherein the memory read clock signal is a clock signal returned from the memory device in response to the memory write clock signal.

16 The memory module of claim 14 further comprising a dummy load coupled to a transmission path of the memory read clock signal and the memory write clock signal.

17 The memory module of claim 14 further comprising a phase locked loop or delay locked loop coupled to a transmission path of the memory read clock signal and the memory write clock signal.

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18 The memory module of claim 12 wherein the first memory module generates a second read clock signal in response to the first write clock signal for transmitting data from the second buffer in the second direction of transmission if the read command indicates that data is to be read from the second memory module in the memory system.

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19 The memory module of claim 12 wherein the second buffer receives a decoding signal generated from the first buffer to determine whether data access is from the memory device on the first memory module or the memory device on the second memory module.

20 The memory module of claim 12 wherein the first buffer receives a first latency signal and transfers a buffered first latency signal to the memory device in response to the first write clock signal

21 The memory module of claim 20 wherein the first buffer generates a second latency signal in response to the first latency signal.

22 The memory module of claim 12 wherein the second write clock signal is generated by a phase locked loop or delay locked loop on the first memory module in response to the first write clock signal.

23 A memory module for use in a memory system comprising:

a first memory module including a memory device and a buffer, the buffer receiving a first write clock signal and a control signal that includes a read or write command in a first direction of transmission, the buffer receiving a first read clock signal in a second direction of transmission, the buffer being coupled to a first data bus and a second data bus; and

the first memory module generating a memory write clock signal in response to the first write clock signal for writing data from the buffer to the memory device if the write command indicates that data is to be written to the memory device in the first module.

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31 The memory module of claim 23 wherein the buffer comprises a first buffer and a second
 buffer, the second buffer receiving a decoding signal generated from the first buffer to
 determine whether data access is from the memory device on the first memory module or
 the memory device on the second memory module

32 The memory module of claim 27 wherein the first buffer receives a first latency signal and
 transfers the buffered first latency signal to the memory device in response to the first write
 clock signal.

33 The memory module of claim 28 wherein the first buffer generates a second latency signal
 in response to the first latency signal.

34 A memory module for use in a memory system comprising:
 a first memory module including a memory device and a buffer, the buffer
 receiving a first write clock signal and a control signal that includes a read or write
 command in a first direction of transmission, the buffer receiving a first read clock signal
 in a second direction of transmission, the buffer being coupled to a first data bus and a
 second data bus; and
 the first memory module generating a memory read clock signal in response to a
 memory write clock signal for reading data from the memory device to the buffer if the
 read command indicates that data is to be read from the memory device in the first memory
 module; the memory write clock signal being generated in response to the first write clock
 signal..

35 The memory module of claim 34 wherein the first memory module generates a second
 write clock signal in response to the first write clock signal for transmitting data from the
 buffer in the first direction of transmission if the write command indicates that data is to be
 written to a second memory module in the memory system.

36 The memory module of claim 34 wherein the first memory module generates a memory write clock signal in response to the first write clock signal for writing data from the buffer to the memory device if the write command indicates that data is to be written to the memory device in the first memory module.

37 The memory module of claim 34 wherein the first memory module generates a second read clock signal in response to the first write clock signal for transmitting data from the buffer in the second direction of transmission if the read command indicates that data is to be read from a second memory module in the memory system.

38 The memory module of claim 34 wherein the buffer comprises a first buffer and a second buffer, the second buffer receiving a decoding signal generated from the first buffer to determine whether data access is from the memory device on the first memory module or the memory device on the second memory module

39 The memory module of claim 38 wherein the first buffer receives a first latency signal and transfers the buffered first latency signal to the memory device in response to the first write clock signal

40 The memory module of claim 39 wherein the first buffer generates a second latency signal in response to the first latency signal.

41 A memory module for use in a memory system comprising:

a first memory module including a memory device and a buffer, the buffer receiving a first write clock signal and a control signal that includes a read or write command in a first direction of transmission, the buffer receiving a first read clock signal in a second direction of transmission, the buffer being coupled to a first data bus and a second data bus; and

the first memory module generating a second read clock signal in response to the

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first write clock signal for transmitting data from the buffer in the second direction of transmission if the read command indicates that data is to be read from a second memory module in the memory system.

5 42 The memory module of claim 41 wherein the first memory module generates a second write clock signal in response to the first write clock signal for transmitting data from the buffer in the first direction of transmission if the write command indicates that data is to be written to the second memory module in the memory system.

10 43 The memory module of claim 41 wherein the first memory module generates a memory write clock signal in response to the first write clock signal for writing data from the buffer to the memory device if the write command indicates that data is to be written to the memory device in the first memory module.

20 44 The memory module of claim 41 wherein the memory module generates a memory read clock signal in response to a memory write clock signal for reading data from the memory device to the buffer if the read command indicates that data is to be read from the memory device in the first memory module, the memory write clock signal being generated in response to the first write clock signal..

25 45 A memory system comprising:

a memory controller for generating a first write clock signal and a control signal that includes a read or write command; and

a first memory module including a memory device and a buffer, the buffer receiving the first write clock signal and the control signal in a first direction of transmission, the buffer receiving a first read clock signal in a second direction of transmission, the buffer being coupled to a first data bus and a second data bus;

the first memory module generating a second write clock signal in response to the first write clock signal for transmitting data from the buffer in the first

direction of transmission if the write command indicates that data is to be written to a second memory module in the memory system, and generating a memory write clock signal in response to the first write clock signal for writing data from the buffer to the memory device if the write command indicates that data is to be written to the memory device in the first memory module; and

the first memory module generating a memory read clock signal in response to the memory write clock signal for reading data from the memory device to the buffer if the read command indicates that data is to be read from the memory device in the first memory module.

46 A memory system comprising:

a memory controller for generating a first write clock signal and a control signal that includes a read or write command;

a read clock generator for generating a first read clock signal; and

a first memory module including a memory device and a buffer, the buffer receiving the first write clock signal and the control signal in a first direction of transmission, the buffer receiving the first read clock signal in a second direction of transmission, the buffer being coupled to a first data bus and a second data bus;

the first memory module generating a second write clock signal in response to the first write clock signal for transmitting data from the buffer in the first direction of transmission if the write command indicates that data is to be written to a second memory module in the memory system, and generating a memory write clock signal in response to the first write clock signal for writing data from the buffer to the memory device if the write command indicates that data is to be written to the memory device in the first memory module;

the first memory module generating a memory read clock signal in response to the memory write clock signal for reading data from the memory to the buffer if the read command indicates that data is to be read from the memory device in the first memory module; and

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the first memory module generating a second read clock signal in response to the first read clock signal for transmitting data from the buffer in the second direction of transmission.

5 47 A method for generating clock signals in a memory system comprising:

receiving, at a first buffer on a first memory module including a memory device, a first write clock signal and a control signal that includes a read or write command in a first direction of transmission;

10 receiving, at a second buffer on the first memory module, the first write clock signal in the first direction of transmission and a first read clock signal in a second direction of transmission, the second buffer being coupled to a first data bus and a second data bus;

generating a second write clock signal in response to the first write clock signal for transmitting data from the second buffer in the first direction of transmission if the write command indicates that data is to be written to a second memory module in the memory system, and generating a memory write clock signal in response to the first write clock signal for writing data from the second buffer to the memory device if the write command indicates that data is to be written to the memory device in the first memory module; and

20 generating a memory read clock signal in response to a memory write clock signal for reading data from the memory device to the second buffer if the read command indicates that data is to be read from the memory device in the first memory module; the memory write clock signal being generated in response to the first write clock signal.

48 A method for generating clock signals in a memory system comprising:

25 receiving, at a first buffer on a first memory module including a memory device, a first write clock signal and a control signal that includes a read or write command in a first direction of transmission,

receiving, at a second buffer on the first memory module, the first write clock signal in the first direction of transmission and a first read clock signal in a second direction

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of transmission, the second buffer being coupled to a first data bus and a second data bus;
and

generating a second write clock signal in response to the first write clock signal for
transmitting data from the second buffer in the first direction of transmission if the write
command indicates that data is to be written to a second memory module in the memory
system.

49 A method for generating a clock signal in a memory system comprising:

receiving, at a buffer on a first memory module including a memory device, a first
write clock signal and a control signal that includes a read or write command in a first
direction of transmission,

receiving a first read clock signal in a second direction of transmission, the buffer
being coupled to a first data bus and a second data bus; and

generating a memory write clock signal in response to the first write clock signal
for writing data from the buffer to the memory device if the write command indicates that
data is to be written to the memory device in the first module.

50 A method for generating a clock signal in a memory system comprising:

receiving, at a buffer on a first memory module including a memory device, a first
write clock signal and a control signal that includes a read or write command in a first
direction of transmission;

receiving a first read clock signal in a second direction of transmission, the buffer
being coupled to a first data bus and a second data bus;

generating, in response to the first write clock signal, a memory write clock signal;
and

generating a memory read clock signal in response to the memory write clock
signal for reading data from the memory device to the buffer if the read command indicates
that data is to be read from the memory device in the first memory module.

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- 51 A method for generating a clock signal in a memory system comprising:
- receiving, at a buffer on a first memory module including a memory device, a first write clock signal and a control signal that includes a read or write command in a first direction of transmission;
 - 5 receiving a first read clock signal in a second direction of transmission, the buffer being coupled to a first data bus and a second data bus; and
 - generating a second read clock signal in response to the first write clock signal for transmitting data from the buffer in the second direction of transmission if the read command indicates that data is to be read from a second memory module in the memory system.
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